PATENT#25

DOCKET NO.: PUAS-0016/98-152-2-1

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In Re Application of:

Stephen R. Forrest, Milind R. Gokhale

and Pavel Studenkov

Confirmation No.: 8094

Application No.: 09/982,001

Group Art Unit: 2874

Filing Date: October 18, 2001

Examiner: Ullah, Akm E.

For: TWIN WAVEGUIDE BASED DESIGN FOR PHOTONIC INTEGRATED

CIRCUITS

VIA HAND DELIVERY
Date of Deposit: February 8, 2006

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

Pursuant to 37 CFR § 1.56 and in accordance with 37 CFR §§ 1.97-1.98, information relating to the above-identified application is hereby disclosed. Inclusion of information in this statement is not to be construed as an admission that this information is material as that term is defined in 37 CFR § 1.56(b).

In accordance with § 1.97(b), since this Information Disclosure Statement is being filed either within three months of the filing date of the above-identified application, within three months of the date of entry into the national stage of the above identified application as set forth in § 1.491, before the mailing date of a first Office Action on the merits of the above-identified application, or

	before the mailing date of a first Office Action after the filing of request for
	continued examination under § 1.114, no additional fee is required.
	In accordance with § 1.97(c), this Information Disclosure Statement is being
	filed after the period set forth in § 1.97(b) above but before the mailing date of
	either a Final Action under § 1.116 or a Notice of Allowance under § 1.311, or
	before an action that otherwise closes prosecution in the application, therefore:
	Certification in Accordance with § 1.97(e) is attached; or
	The fee of $$180.00$ as set forth in $$1.17(p)$ is attached.
	In accordance with § 1.97(d), this Information Disclosure Statement is being
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	of Allowance under § 1.311 but before, or simultaneously with, the payment
	of the Issue Fee, therefore included are: Certification in Accordance with §
	1.97(e); and the submission fee of <u>\$180.00</u> as set forth in § 1.17(p).
\boxtimes	Copies of reference numbers 40 – 99 listed on the attached Form PTO-1449
	are enclosed herewith.
	Copies of reference numbers on the attached Form PTO 1449 are not
	required to be submitted pursuant to 37 CFR § 1.98(a)(2)(i).
	Copies of references - are not being submitted because
	they were previously cited by or submitted to the U.S. Patent and
	Trademark Office in patent application number , filed for
	which a claim for priority under 35 U.S.C. § 120 has been made in the
	instant application.
The re	elevance of those listed references which are not in the English language is as
follow	vs:

There are no listed references which are not in the English language.

Enclosed is a copy of a Communication Pursuant to Article 96(2) EPC dated March 3, 2005 that was received in a related application before the European Patent Office and identifies several references.

Please charge any deficiency or credit any overpayment to Deposit Account No. 23-3050. This form is submitted in duplicate.

Date: February 7, 2006

John E. McGlynn / Registration No. 42,863

WOODCOCK WASHBURN LLP One Liberty Place - 46th Floor Philadelphia, PA 19103 Telephone: (215) 568-3100

Facsimile: (215) 568-3439

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